

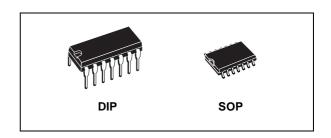


# TRIPLE 3 INPUT AND GATE

- MEDIUM SPEED OPERATION:  $t_{PD} = 60$ ns (TYP.) at  $V_{DD} = 10$ V
- QUIESCENT CURRENT SPECIFIED UP TO
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I<sub>I</sub> = 100nA (MAX) AT V<sub>DD</sub> = 18V T<sub>A</sub> = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B " STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

#### **DESCRIPTION**

The HCF4073B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. The HCF4073B TRIPLE 3 INPUT AND GATE provides the system designer with direct

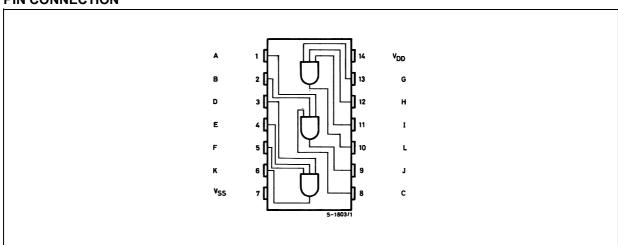


#### **ORDER CODES**

PACKAGE	TUBE	T&R
DIP	HCF4073BEY	
SOP	HCF4073BM1	HCF4073M013TR

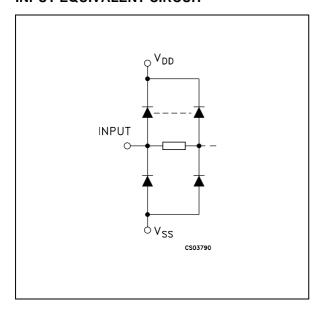
implementation of the AND function and supplement the existing family of CMOS gates.

### **PIN CONNECTION**



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### **INPUT EQUIVALENT CIRCUIT**



### **PIN DESCRIPTION**

PIN No	SYMBOL	NAME AND FUNCTION
13, 8, 5	G, C, F	Data Inputs
12, 2, 4	H, B, E	Data Inputs
11, 1, 3	I, A, D	Data Inputs
10, 9, 6	L, J, K	Data Outputs
7	$V_{SS}$	Negative Supply Voltage
14	$V_{DD}$	Positive Supply Voltage

### **TRUTH TABLE**

	INPUTS		OUTPUTS
G, C, F	Н, В, Е	I, A, D	L, J , K
L	X	X	L
X	L	X	L
Х	X	L	L
Н	Н	Н	Н

X : Don't Care

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.5 to +22	V
VI	DC Input Voltage	-0.5 to V <sub>DD</sub> + 0.5	V
I <sub>I</sub>	DC Input Current	± 10	mA
$P_{D}$	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T <sub>op</sub>	Operating Temperature	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V<sub>SS</sub> pin voltage.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	3 to 20	V
VI	Input Voltage	0 to V <sub>DD</sub>	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C

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### **DC SPECIFICATIONS**

			Test Con	dition					Value				
Symbol	Parameter	Vı	v <sub>o</sub>	ΙΙ <sub>Ο</sub> Ι	V <sub>DD</sub>	Т	A = 25°	С	-40 to	85°C	-55 to	125°C	Unit
		(V)	(V)	(μ <b>A</b> ) (V)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.01	0.25		7.5		7.5	
		0/10			10		0.01	0.5		15		15	^
		0/15			15		0.01	1		30		30	μΑ
		0/20			20		0.02	5		150		150	
V <sub>OH</sub>	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
V <sub>OL</sub>	Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
$V_{IH}$	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		>
	Voltage		1/9	<1	10	7			7		7		
			1.5/13.5	<1	15	11			11		11		
$V_{IL}$	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I <sub>OH</sub>	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.15		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		IIIA
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
I <sub>OL</sub>	Output Sink		0.36		0.36								
	Current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mΑ
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
lı	Input Leakage Current	0/18	Any In	put	18		±10 <sup>-5</sup>	±0.1		±1		±1	μΑ
C <sub>I</sub>	Input Capacitance		Any In	put			5	7.5					pF

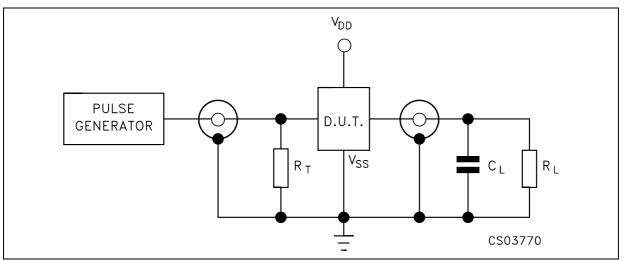
The Noise Margin for both "1" and "0" level is: 1V min. with  $V_{DD}$ =5V, 2V min. with  $V_{DD}$ =10V, 2.5V min. with  $V_{DD}$ =15V

# $\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (T_{amb} = 25^{\circ}C, \;\; C_{L} = 50 pF, \; R_{L} = 200 K\Omega, \;\; t_{f} = t_{f} = 20 \; ns)$

Cumbal	Davamatar		'	Unit			
Symbol	Parameter	V <sub>DD</sub> (V)		Min.	Тур.	Max.	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time	5			125	250	
		10			60	125	ns
		15			45	90	
t <sub>TLH</sub> t <sub>THL</sub>	Output Transition Time	5			100	200	
		10			60	100	ns
		15			40	80	

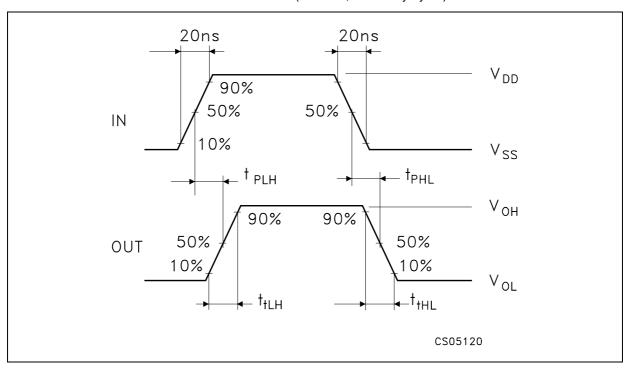
(\*) Typical temperature coefficient for all V<sub>DD</sub> value is 0.3 %/°C.

### **TEST CIRCUIT**



 $C_L$  = 50pF or equivalent (includes jig and probe capacitance)  $R_L$  = 200KΩ  $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50Ω)

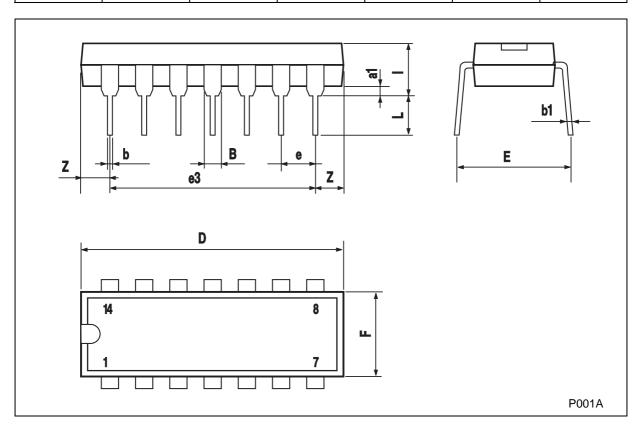
## WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



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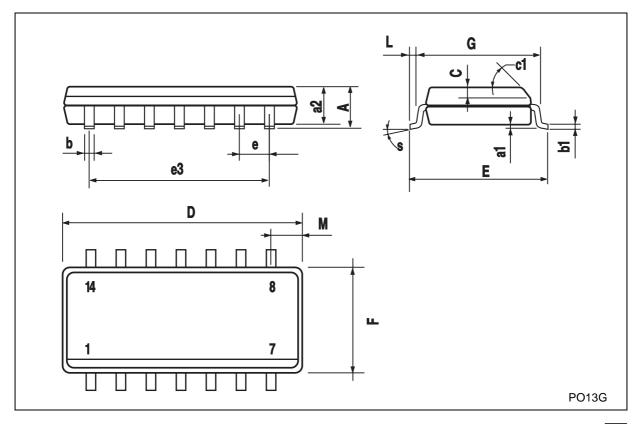
# **Plastic DIP-14 MECHANICAL DATA**

DIM.		mm.				
DIIVI.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



# **SO-14 MECHANICAL DATA**

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)	•			
D	8.55		8.75	0.336		0.344		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
еЗ		7.62			0.300			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.68			0.026		
S			8° (ı	max.)				



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